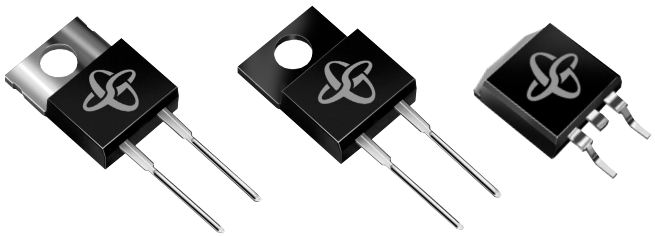
GENERAL SEMICONDUCTOR®

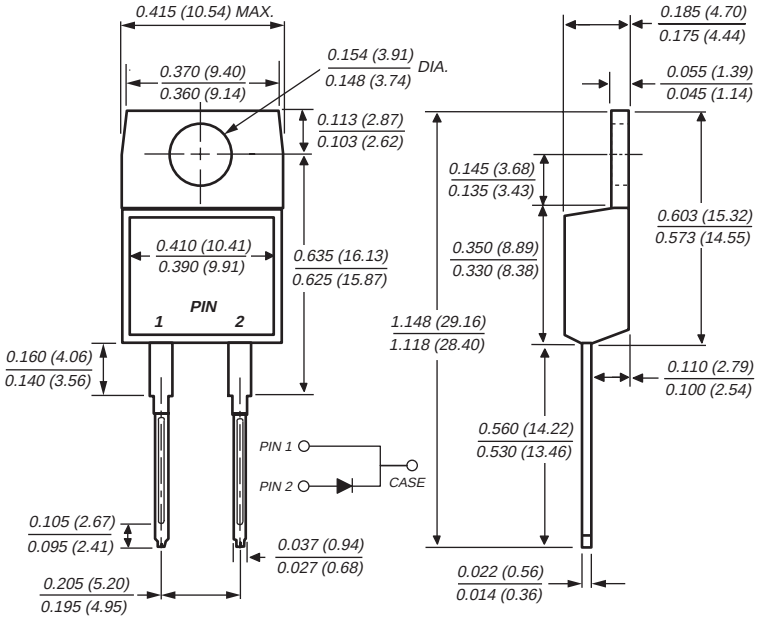
MBR7xx, MBRF7xx & MBRB7xx Series

Schottky Barrier Rectifier

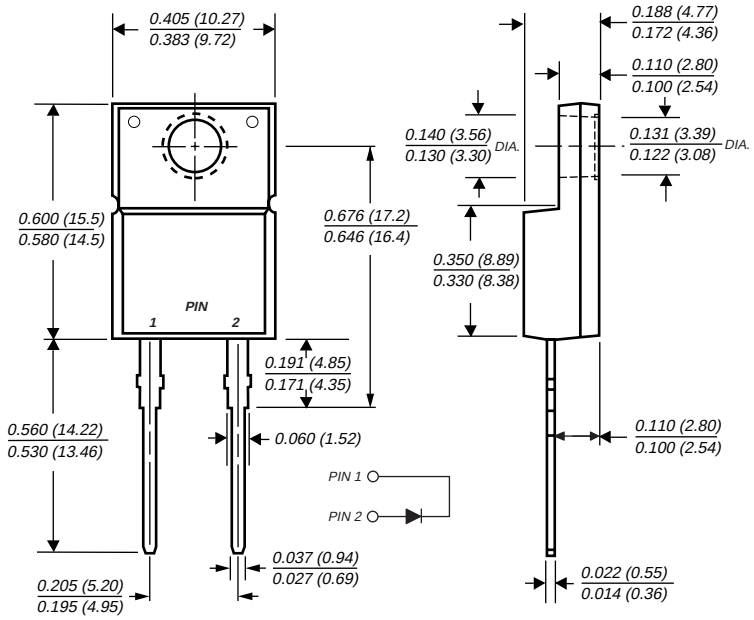
Reverse Voltage 35 to 60 V
Forward Current 7.5 A



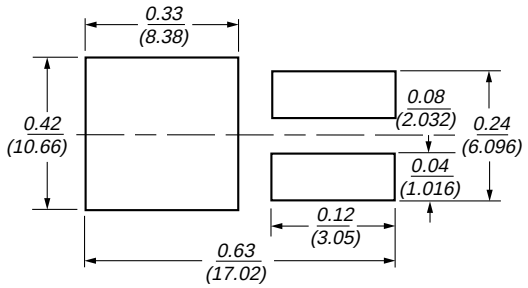
TO-220AC (MBR7xx)



ITO-220AC (MBRF7xx)

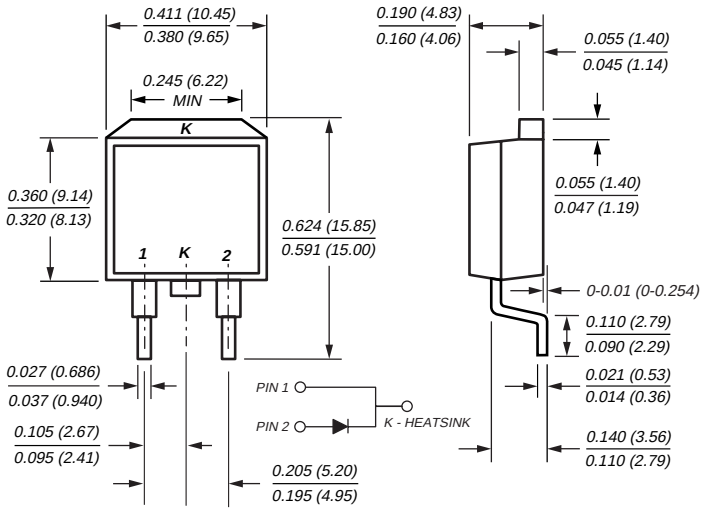


Mounting Pad Layout TO-263AB



Dimensions in inches and (millimeters)

TO-263AB (MBRB7xx)



Features

- Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Guardring for overvoltage protection
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case

Mechanical Data

Case: JEDEC TO-220AC, ITO-220AC & TO-263AB molded plastic body

Terminals: Plated leads, solderable per MIL-STD-750, Method 2026

Polarity: As marked

Mounting Position: Any

Mounting Torque: 10 in-lbs maximum

Weight: 0.08 ounce, 2.24 grams

1/10/00

GENERAL SEMICONDUCTOR®

MBR7xx, MBRF7xx & MBRB7xx Series

Schottky Barrier Rectifier

Maximum Ratings (T_C = 25°C unless otherwise noted)

Parameter	Symbol	MBR735	MBR745	MBR750	MBR760	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50	60	V
Working peak reverse voltage	V_{RWM}	35	45	50	60	V
Maximum DC blocking voltage	V_{DC}	35	45	50	60	V
Maximum average forward rectified current (SEE FIG. 1)	$I_{F(AV)}$	7.5				A
Peak repetitive forward current (sq. wave, 20 KHz) at T_C = 105°C	I_{FRM}	15				A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150				A
Peak repetitive reverse current per leg at t_p = 2.0µs, 1KHz	I_{RRM}	1.0		0.5		A
Voltage rate of change (rated V_R)	dv/dt	10,000				V/µs
Operating junction temperature range	T_J	–65 to +150				°C
Storage temperature range	T_{STG}	–65 to +175				°C
RMS Isolation voltage (MBRF type only) from terminals to heatsink with t = 1.0 second, RH ≤ 30%	V_{ISOL}	4500 (NOTE 1) 3500 (NOTE 2) 1500 (NOTE 3)				V

Electrical Characteristics (T_C = 25°C unless otherwise noted)

Parameter		Symbol	MBR735	MBR745	MBR750	MBR760	Unit
Maximum instantaneous forward voltage per leg (Note 4)							
at I_F = 7.5A,	T_C = 25°C	V_F	–		0.75		V
at I_F = 7.5A,	T_C = 125°C		0.57		0.65		
at I_F = 15A,	T_C = 25°C		0.84		–		
at I_F = 15A,	T_C = 125°C		0.72		–		
Maximum reverse current	T_C = 25°C	I_R	0.1		0.5		mA
at DC blocking voltage	T_C = 125°C		15		50		

Thermal Characteristics (T_C = 25°C unless otherwise noted)

Parameter	Symbol	MBR	MBRF	MBRB	Unit
Thermal resistance from junction to case and/or thermal resistance from junction to ambient	$R_{\Theta JA}$ $R_{\Theta JC}$	60 3.0	— 5.0	60 3.0	°C/W

Notes:
(1) Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset
(2) Clip mounting (on case), where leads do overlap heatsink
(3) Screw mounting with 4-40 screw, where washer diameter is ≤ 4.9 mm (0.19")
(4) Pulse test: 300µs pulse width, 1% duty cycle

Ratings and Characteristic Curves (T_A = 25°C unless otherwise noted)

FIG. 1 - FORWARD CURRENT DERATING CURVE

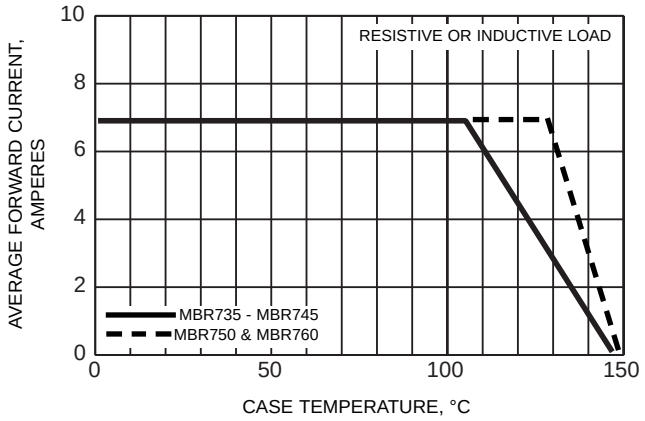


FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

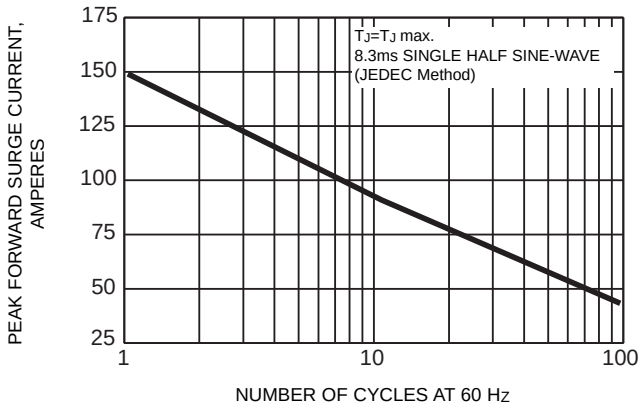


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

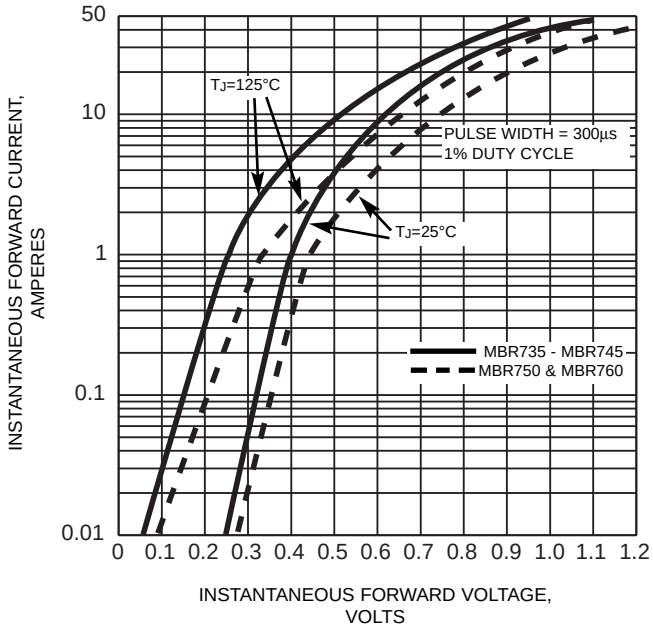


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

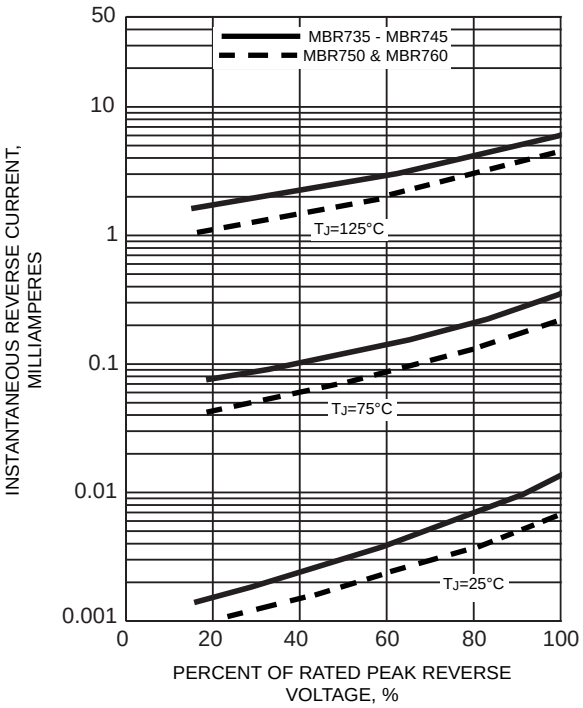


FIG. 5 - TYPICAL JUNCTION CAPACITANCE

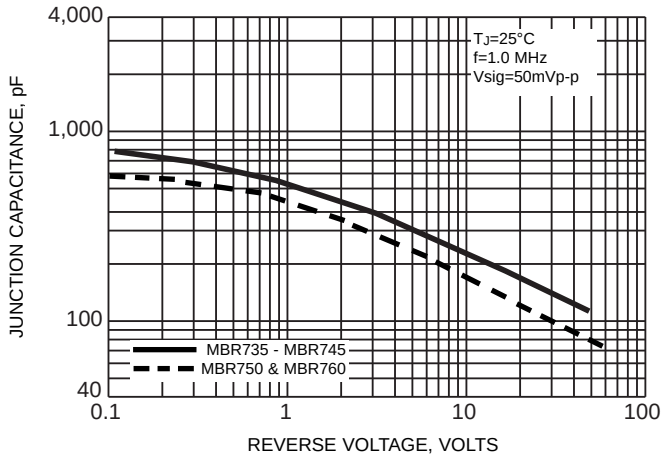


FIG. 6 - TYPICAL TRANSIENT THERMAL IMPEDANCE